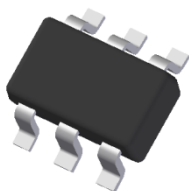


SMALL SIGNAL COMPLEMENTARY PRE-BIASED DUAL TRANSISTOR
Features

- Epitaxial Planar Die Construction
- Built-In Biasing Resistors
- Surface Mount Package Suited for Automated Assembly
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

Part Number	R1(NOM)	R2(NOM)
DCX124EU	22kΩ	22kΩ
DCX144EU	47kΩ	47kΩ
DCX114YU	10kΩ	47kΩ
DCX123JU	2.2kΩ	47kΩ
DCX114EU	10kΩ	10kΩ
DCX143EU	4.7kΩ	4.7kΩ
DCX143ZU	4.7kΩ	47kΩ
DCX115EU	100kΩ	100kΩ

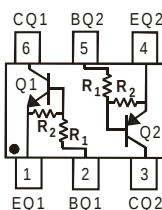
SOT363


Top View

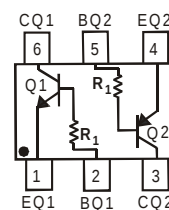
Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)

Part Number	R1 Only
DCX143TU	4.7kΩ
DCX114TU	10kΩ



R1, R2



R1 Only

Device Schematic

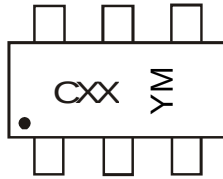
Ordering Information (Notes 4, 5 & 6)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DCX124EU-7-F	Active	AEC-Q101	C17	7	8	3,000
DCX124EUQ-7-F	NRND (Use ACX124EUQ)	Automotive	C17	7	8	3,000
DCX124EUQ-13-F	NRND (Use ACX124EUQ)	Automotive	C17	13	8	10,000
DCX124EUQ-13R-F	NRND (Use ACX124EUQ)	Automotive	C17	13	8	10,000
DCX144EU-7-F	Active	AEC-Q101	C20	7	8	3,000
DCX144EU-7R-F	Active	AEC-Q101	C20	7	8	3,000
DCX144EUQ-7-F	Active	Automotive	C20	7	8	3,000
DCX114YU-7-F	Active	AEC-Q101	C14	7	8	3,000
DCX114YUQ-7-F	NRND (Use ACX114YUQ)	Automotive	C14	7	8	3,000
DCX114YUQ-13-F	NRND (Use ACX114YUQ)	Automotive	C14	13	8	10,000
DCX114YUQ-13R-F	NRND (Use ACX114YUQ)	Automotive	C14	13	8	10,000
DCX123JU-7-F	Active	AEC-Q101	C06	7	8	3,000
DCX123JUQ-7-F	Active	Automotive	C06	7	8	3,000
DCX114EU-7-F	Active	AEC-Q101	C13	7	8	3,000
DCX114EU-13R-F	Active	AEC-Q101	C13	13	8	10,000
DCX114EUQ-7-F	NRND (Use ACX114EUQ)	Automotive	C13	7	8	3,000
DCX114EUQ-13-F	NRND (Use ACX114EUQ)	Automotive	C13	13	8	10,000
DCX114EUQ-13R-F	NRND (Use ACX114EUQ)	Automotive	C13	13	8	10,000
DCX143TU-7-F	Active	AEC-Q101	C07	7	8	3,000
DCX143EU-7-F	Active	AEC-Q101	C08	7	8	3,000
DCX114TU-7-F	Active	AEC-Q101	C12	7	8	3,000
DCX143ZU-7-F	Active	AEC-Q101	C02	7	8	3,000
DCX115EU-7-F	Active	AEC-Q101	C01	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to <http://www.diodes.com/quality/>.
 5. -7R and -13R are parts rotated in the pocket tape by +180°. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.
 6. NRND = Not Recommended for New Design.

Marking Information

SOT363



CXX = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: F = 2018)
M = Month (ex: 9 = September)

Date Code Key

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028
Code	F	G	H	I	J	K	L	M	N	O	P

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage <Pin: (6) to (1)>	V _{CC}	50	V
Input Voltage <Pin: (2) to (1)>	V _{IN}	-10 to +40 -10 to +40 -6 to +40 -5 to +12 -10 to +40 -5V Max -10 to +30 -5V Max -10 to +30 -10 to +40	V
Output Current	I _O	30 30 70 100 50 100 100 100 100 20	mA
Output Current	I _C (Max)	100	mA

Absolute Maximum Ratings PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage <Pin: (4) to (3)>		V _{CC}	50	V
Input Voltage <Pin: (5) to (4)>	DCX124EU	V _{IN}	+10 to -40	V
	DCX144EU		+10 to -40	
	DCX114YU		+6 to -40	
	DCX123JU		+5 to -12	
	DCX114EU		+10 to -40	
	DCX143TU		+5V Max	
	DCX143EU		+10 to -30	
	DCX114TU		+5V Max	
	DCX143ZU		+5 to -30	
	DCX115EU		+10 to -40	
Output Current	DCX124EU	I _O	-30	mA
	DCX144EU		-30	
	DCX114YU		-70	
	DCX123JU		-100	
	DCX114EU		-50	
	DCX143TU		-100	
	DCX143EU		-100	
	DCX114TU		-100	
	DCX143ZU		-100	
	DCX115EU		-20	
Output Current		I _C (Max)	-100	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 7 & 8)	P _D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 7)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 7. Mounted on FR-4 PC Board with minimum recommended pad layout.
8. 150mW per element must not be exceeded.

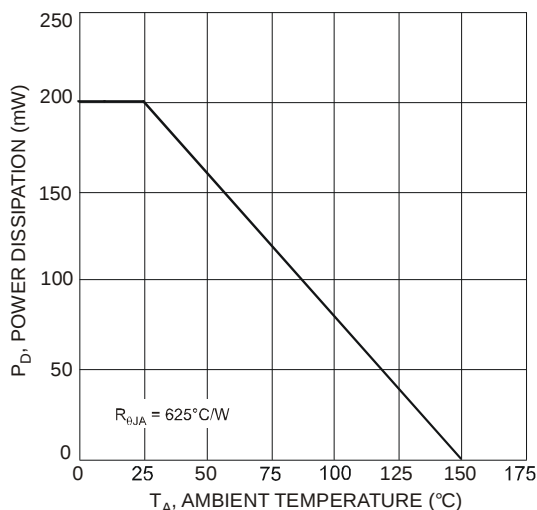
Electrical Characteristics NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
R1 Only (DCX143TU & DCX114TU)							
Collector-Base Breakdown Voltage		BV _{CBO}	50	—	—	V	I _C = 50μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	50	—	—	V	I _C = 1mA
Emitter-Base Breakdown Voltage		BV _{EBO}	5	—	—	V	I _E = 50μA
Collector Cutoff Current		I _{CBO}	—	—	0.5	μA	V _{CB} = 50V
Emitter Cutoff Current		I _{EBO}	—	—	0.5	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage		V _{CE(SAT)}	—	—	0.3	V	I _C /I _B = 2.5mA / 0.25mA DCX143TU I _C /I _B = 1mA / 0.1mA DCX114TU
DC Current Transfer Ratio		h _{FE}	100	250	600	—	I _C = 1mA, V _{CE} = 5V
Input Resistor (R ₁) Tolerance		ΔR ₁	-30	—	+30	%	—
Gain-Bandwidth Product		f _T	—	250	—	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz
R1/R2 Only							
Input Voltage	DCX124EU	V _{I(OFF)}	0.5	1.1	—	V	V _{CC} = 5V, I _O = 100μA
	DCX144EU		0.5	1.1			
	DCX114YU		0.3	—			
	DCX123JU		0.5	—			
	DCX114EU		0.5	1.1			
	DCX143EU		0.5	1.16			
	DCX143ZU		0.5	—			
	DCX115EU		0.5	—			
	DCX124EU	V _{I(ON)}	—	1.9	3.0		V _O = 0.3V, I _O = 5mA
	DCX144EU			1.9	3.0		V _O = 0.3V, I _O = 2mA
	DCX114YU			—	1.4		V _O = 0.3V, I _O = 1mA
	DCX123JU			—	1.1		V _O = 0.3V, I _O = 5mA
	DCX114EU			1.9	3.0		V _O = 0.3V, I _O = 10mA
	DCX143EU			1.99	3.0		V _O = 0.3V, I _O = 20mA
	DCX143ZU			—	1.3		V _O = 0.3V, I _O = 5mA
	DCX115EU			—	3		V _O = 0.3V, I _O = 1mA
Output Voltage	DCX124EU	V _{O(ON)}	—	0.1	0.3	V	I _O /I _I = 10mA / 0.5mA
	DCX144EU						I _O /I _I = 10mA / 0.5mA
	DCX114YU						I _O /I _I = 5mA / 0.25mA
	DCX123JU						I _O /I _I = 5mA / 0.25mA
	DCX114EU						I _O /I _I = 10mA / 0.5mA
	DCX143EU						I _O /I _I = 10mA / 0.5mA
	DCX143ZU						I _O /I _I = 5mA / 0.25mA
	DCX115EU						I _O /I _I = 10mA / 0.5mA
Input Current	DCX124EU	I _I	—	—	0.36	mA	V _I = 5V
	DCX144EU				0.18		
	DCX114YU				0.88		
	DCX123JU				3.6		
	DCX114EU				0.88		
	DCX143EU				0.88		
	DCX143ZU				1.8		
	DCX115EU				0.15		
Output Current		I _{O(OFF)}	—	—	0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	DCX124EU	G _I	56	—	—	—	V _O = 5V, I _O = 5mA
	DCX124EUQ		60				V _O = 5V, I _O = 5mA
	DCX144EU		68				V _O = 5V, I _O = 5mA
	DCX114YU		68				V _O = 5V, I _O = 10mA
	DCX114YUQ		80				V _O = 5V, I _O = 10mA
	DCX123JU		80				V _O = 5V, I _O = 10mA
	DCX114EU		30				V _O = 5V, I _O = 5mA
	DCX143EU		50				V _O = 5V, I _O = 10mA
	DCX143ZU		80				V _O = 5V, I _O = 10mA
	DCX115EU		82				V _O = 5V, I _O = 5mA
Input Resistor (R ₁) Tolerance		ΔR ₁	-30	—	+30	%	—
Resistance Ratio Tolerance		ΔR ₂ /R ₁	-20	—	+20	%	—
Gain-Bandwidth Product		f _T	—	250	—	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

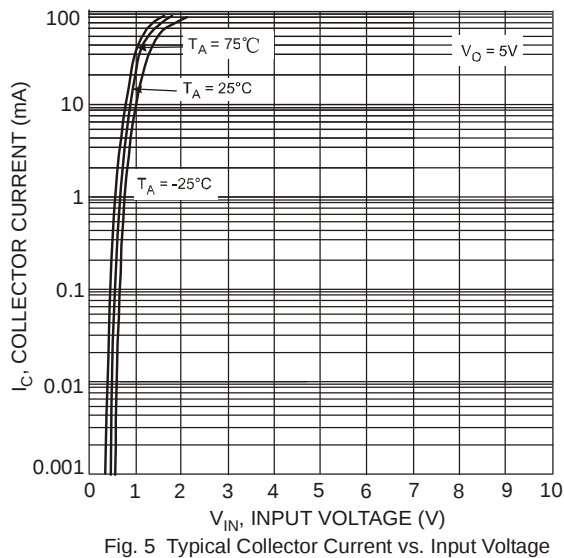
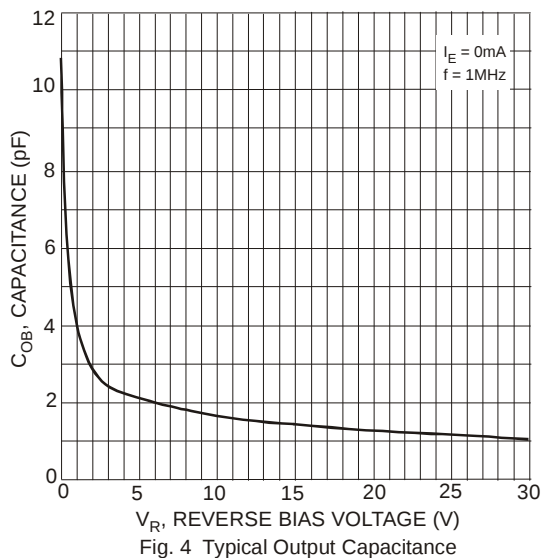
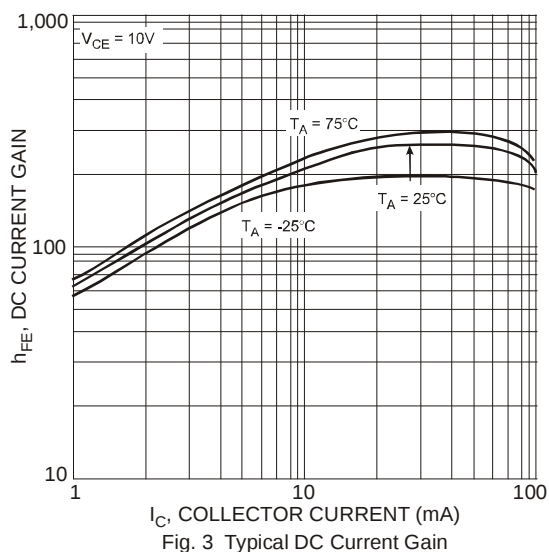
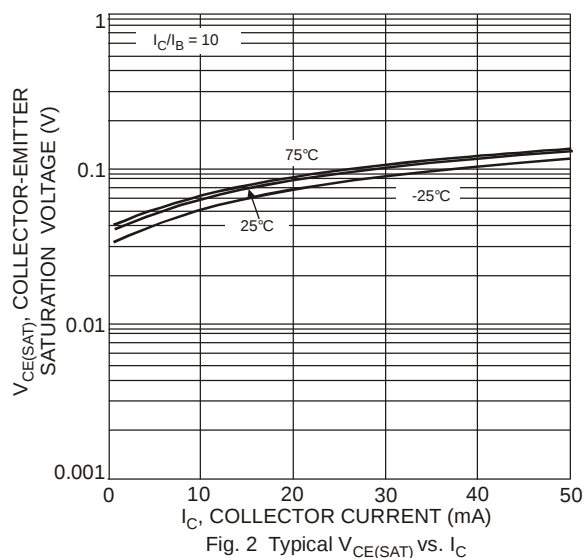
Electrical Characteristics PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
R1 Only (DCX143TU & DCX114TU)							
Collector-Base Breakdown Voltage		BV _{CBO}	-50	—	—	V	I _C = -50μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	-50	—	—	V	I _C = -1mA
Emitter-Base Breakdown Voltage		BV _{EBO}	-5	—	—	V	I _E = -50μA
Collector Cutoff Current		I _{CBO}	—	—	-0.5	μA	V _{CB} = -50V
Emitter Cutoff Current		I _{EBO}	—	—	-0.5	μA	V _{EB} = -4V
Collector-Emitter Saturation Voltage		V _{CE(SAT)}	—	—	-0.3	V	I _C /I _B = 2.5mA / 0.25mA DCX143TU I _C /I _B = 1mA / 0.1mA DCX114TU
DC Current Transfer Ratio		h _{FE}	100	250	600	—	I _C = -1mA, V _{CE} = -5V
Input Resistor (R ₁) Tolerance		ΔR ₁	-30	—	+30	%	—
Gain-Bandwidth Product		f _T	—	250	—	MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz
R1/R2 Only							
Input Voltage	DCX124EU	V _{I(OFF)}	-0.5	-1.1	—	V	V _{CC} = -5V, I _O = -100μA
	DCX144EU		-0.5	-1.1			
	DCX114YU		-0.3	—			
	DCX123JU		-0.5	—			
	DCX114EU		-0.5	-1.1			
	DCX143EU		-0.5	-1.16			
	DCX143ZU		-0.5	—			
	DCX115EU		-0.5	—			
	DCX124EU	V _{I(ON)}	—	-1.9	-3.0		V _O = -0.3V, I _O = -5mA
	DCX144EU		—	-1.9	-3.0		V _O = -0.3V, I _O = -2mA
	DCX114YU		—	—	-1.4		V _O = -0.3V, I _O = -1mA
	DCX123JU		—	—	-1.1		V _O = -0.3V, I _O = -5mA
	DCX114EU		—	-1.9	-3.0		V _O = -0.3V, I _O = -10mA
	DCX143EU		—	-2.5	-3.0		V _O = -0.3V, I _O = -20mA
	DCX143ZU		—	—	-1.3		V _O = -0.3V, I _O = -5mA
	DCX115EU		—	—	-3		V _O = -0.3V, I _O = -1mA
Output Voltage	DCX124EU	V _{O(ON)}	—	-0.1	-0.3	V	I _O /I _I = -10mA / -0.5mA
	DCX144EU						I _O /I _I = -10mA / -0.5mA
	DCX114YU						I _O /I _I = -5mA / -0.25mA
	DCX123JU						I _O /I _I = -5mA / -0.25mA
	DCX114EU						I _O /I _I = -10mA / -0.5mA
	DCX143EU						I _O /I _I = -10mA / -0.5mA
	DCX143ZU						I _O /I _I = -5mA / -0.25mA
Input Current	DCX124EU	I _I	—	—	-0.36	mA	V _I = -5V
	DCX144EU				-0.18		
	DCX114YU				-0.88		
	DCX123JU				-3.6		
	DCX114EU				-0.88		
	DCX143EU				-0.88		
	DCX143ZU				-1.8		
	DCX115EU				-0.15		
Output Current		I _{O(OFF)}	—	—	-0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	DCX124EU	G _I	56	—	—	—	V _O = -5V, I _O = -5mA
	DCX124EUQ		60				V _O = -5V, I _O = -5mA
	DCX144EU		68				V _O = -5V, I _O = -5mA
	DCX114YU		68				V _O = -5V, I _O = -10mA
	DCX114YUQ		80				V _O = -5V, I _O = -10mA
	DCX123JU		80				V _O = -5V, I _O = -10mA
	DCX114EU		30				V _O = -5V, I _O = -5mA
	DCX143EU		40				V _O = -5V, I _O = -10mA
	DCX143ZU		80				V _O = -5V, I _O = -10mA
Input Resistor (R ₁) Tolerance		ΔR ₁	-30	—	+30	%	—
Resistance Ratio Tolerance		ΔR ₂ /R ₁	-20	—	+20	%	—
Gain-Bandwidth Product		f _T	—	250	—	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

Typical Curves – Total Device



Typical Curves – DCX123JU PNP Section (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Typical Curves – DCX123JU PNP Section (Cont.)

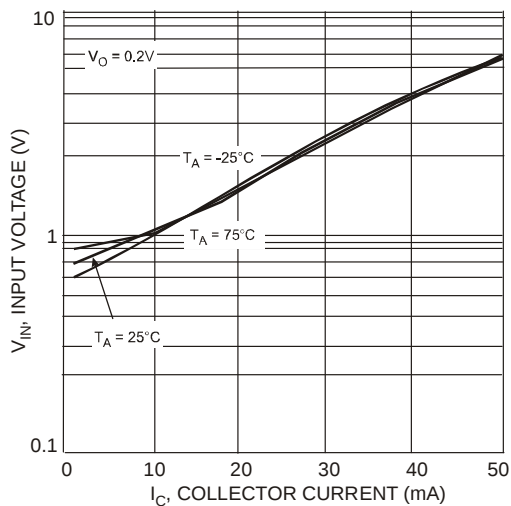


Fig. 6 Typical Input Voltage vs. Collector Current

Typical Curves – DCX123JU NPN Section (@T_A = +25°C, unless otherwise specified.)

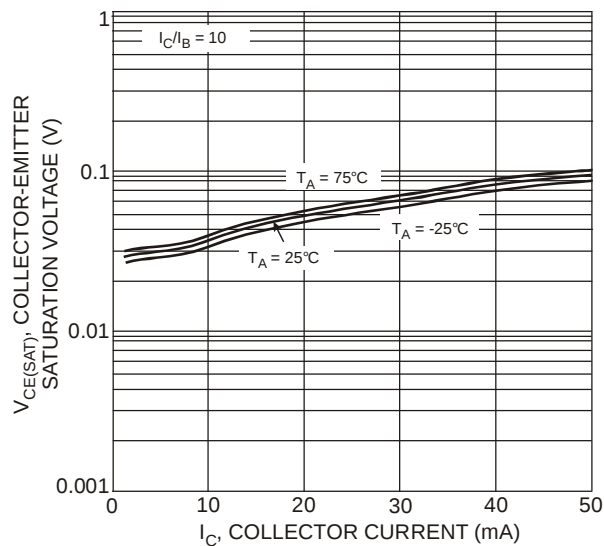


Fig. 7 Typical $V_{CE(SAT)}$ vs. I_C

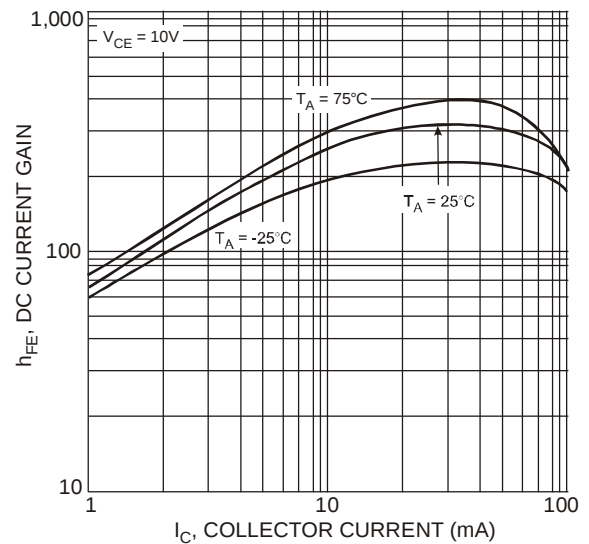


Fig. 8 Typical DC Current Gain

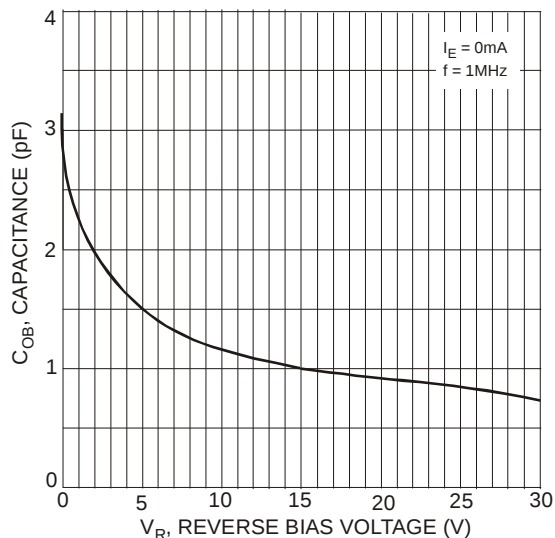


Fig. 9 Typical Output Capacitance

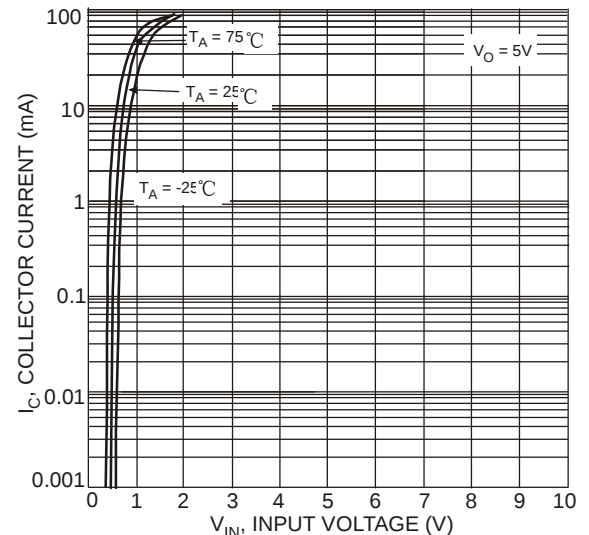
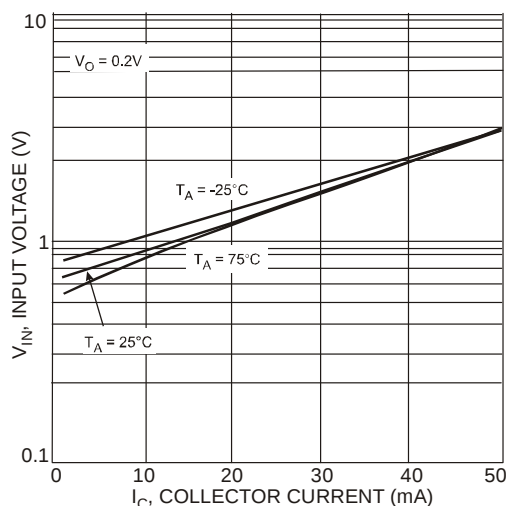
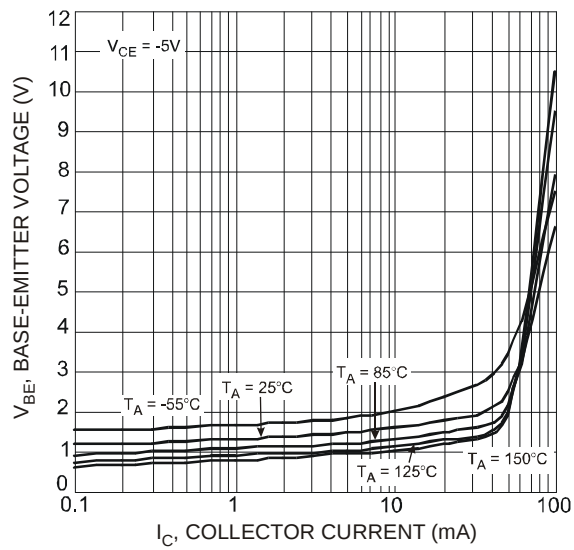
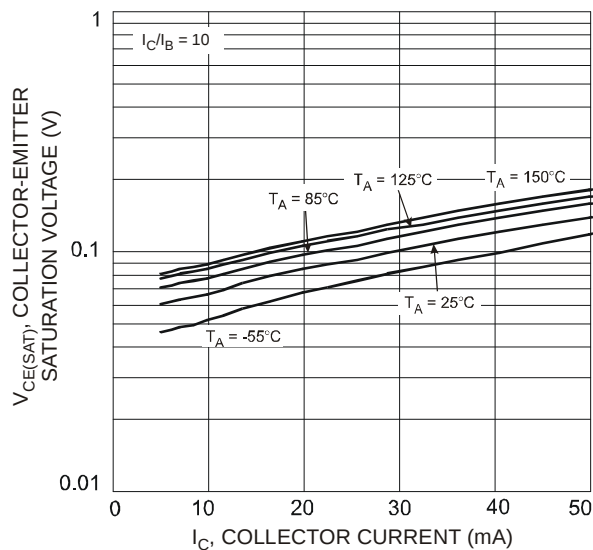
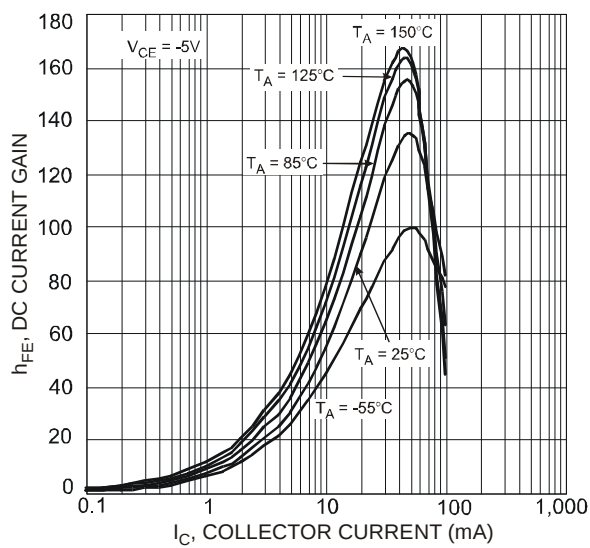
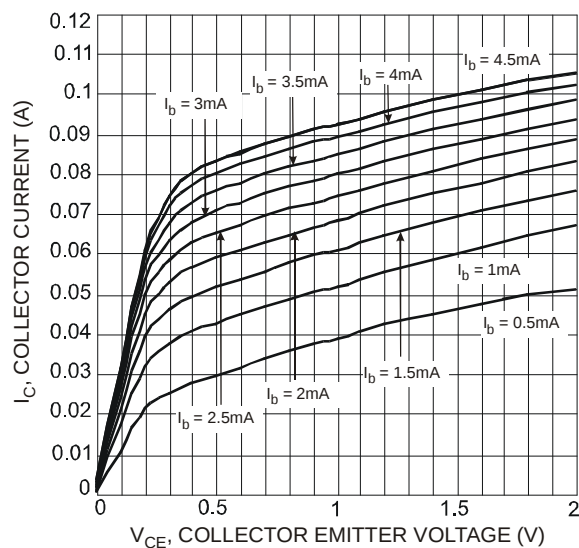


Fig. 10 Typical Collector Current vs. Input Voltage

Typical Curves – DCX123JU NPN Section (Cont.)



Typical Curves – DCX143EU PNP Section (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Typical Curves – DCX143EU PNP Section (Cont.)

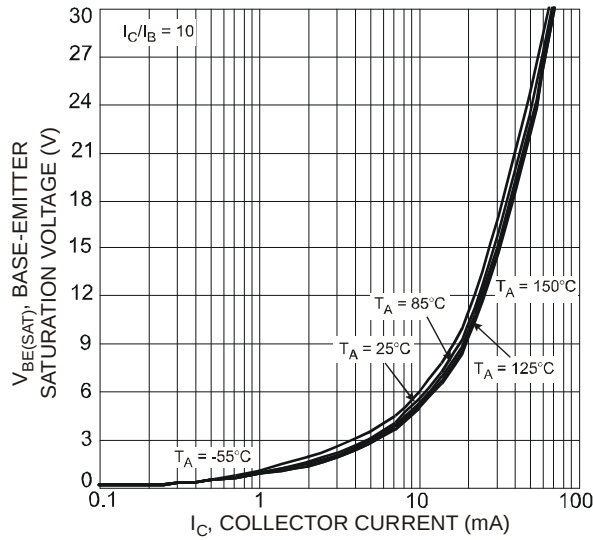


Fig. 16 Typical $V_{BE(SAT)}$ vs. I_C

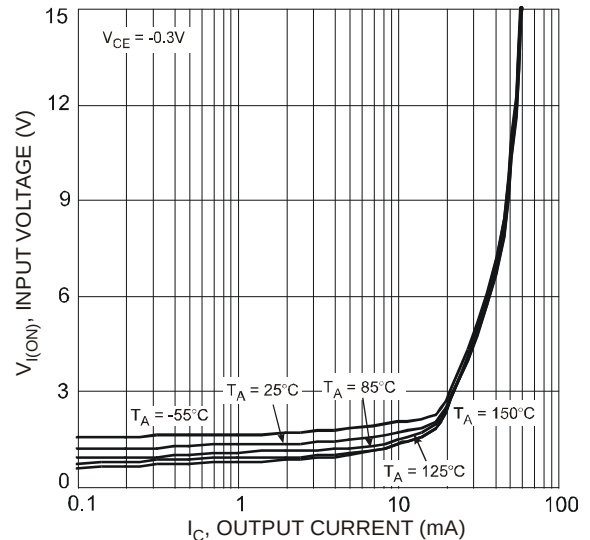


Fig. 17 Typical $V_{I(ON)}$ vs. I_C

Typical Curves – DCX143EU NPN Section (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

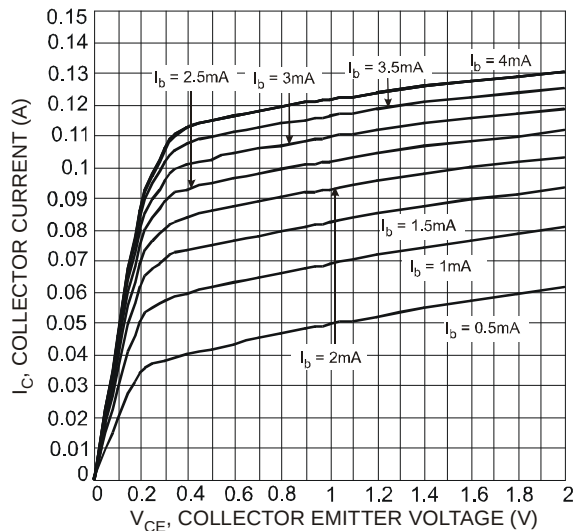


Fig. 18 Typical V_{CE} vs. I_C

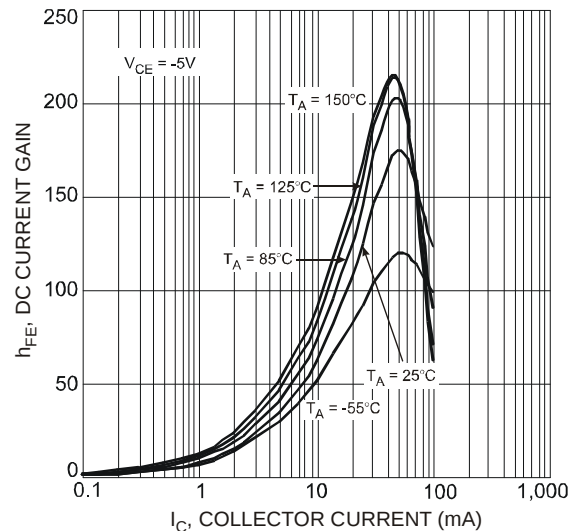


Fig. 19 Typical DC Current Gain

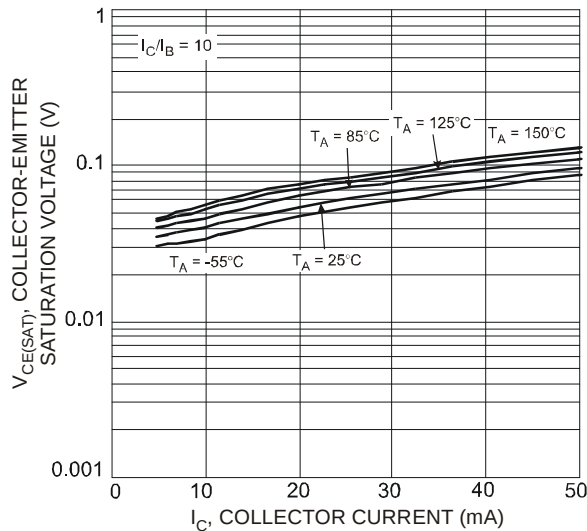


Fig. 20 Typical $V_{CE(SAT)}$ vs. I_C

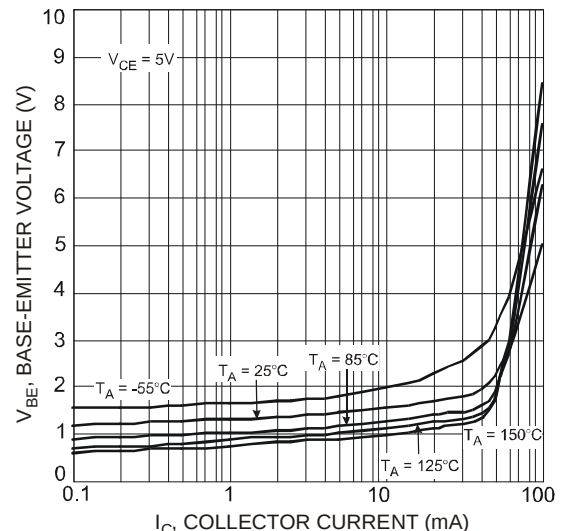
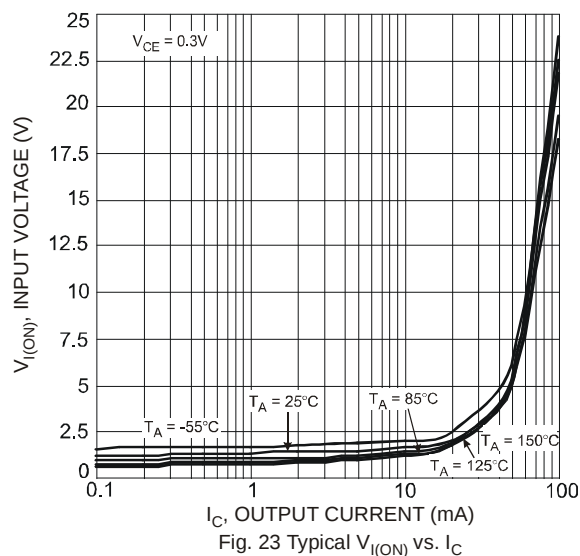
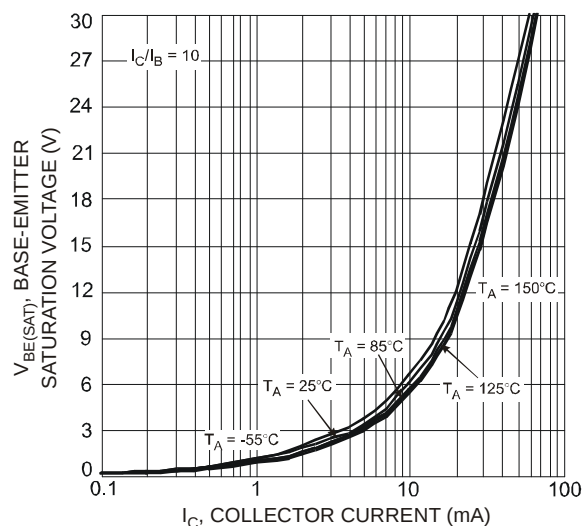
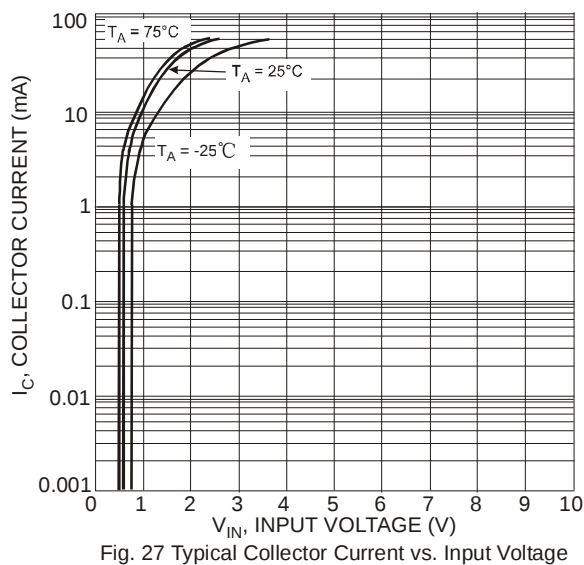
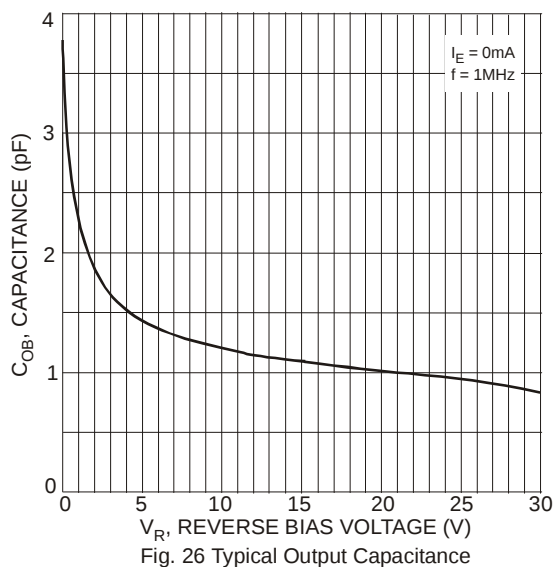
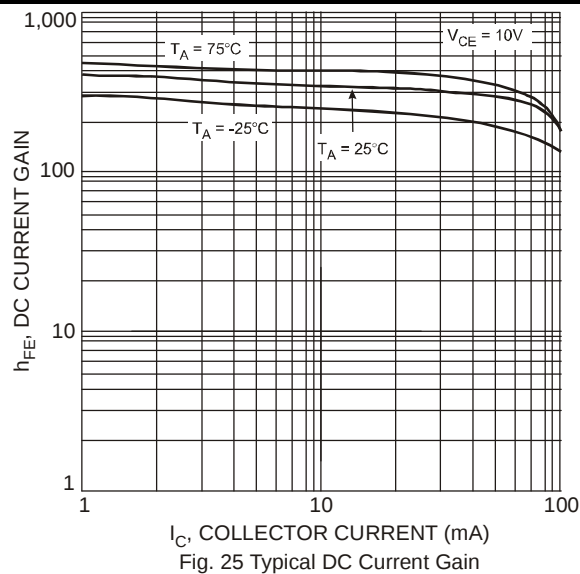
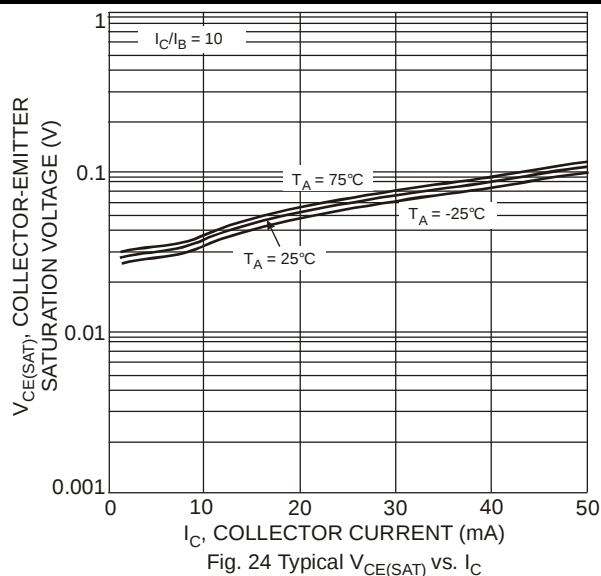


Fig. 21 Typical V_{BE} vs. I_C

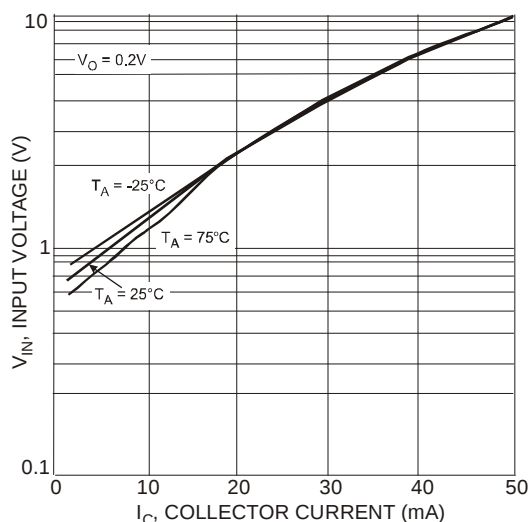
Typical Curves – DCX143EU NPN Section (Cont.)



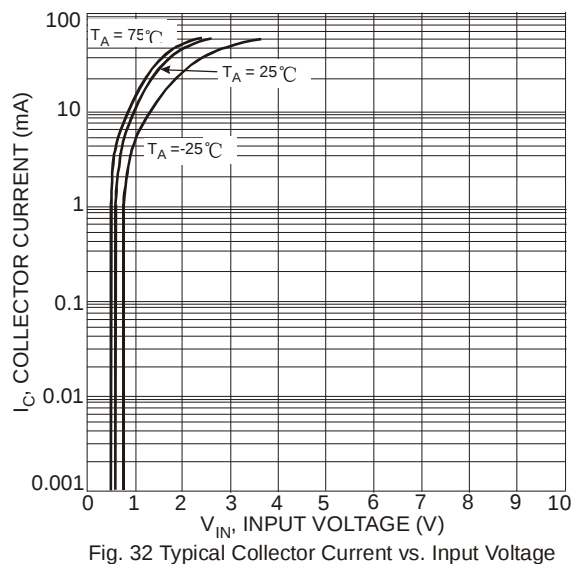
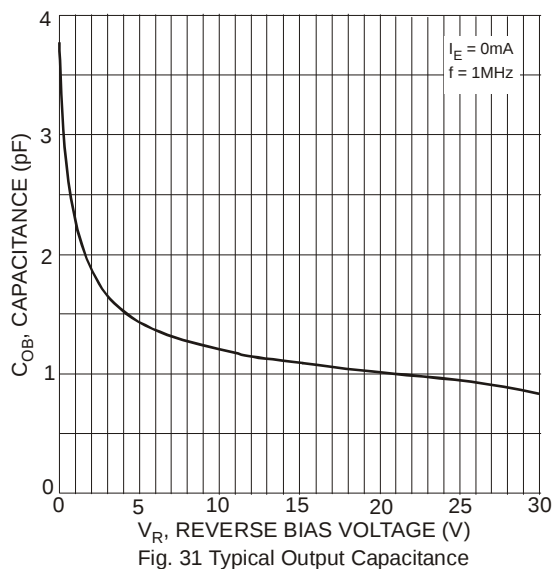
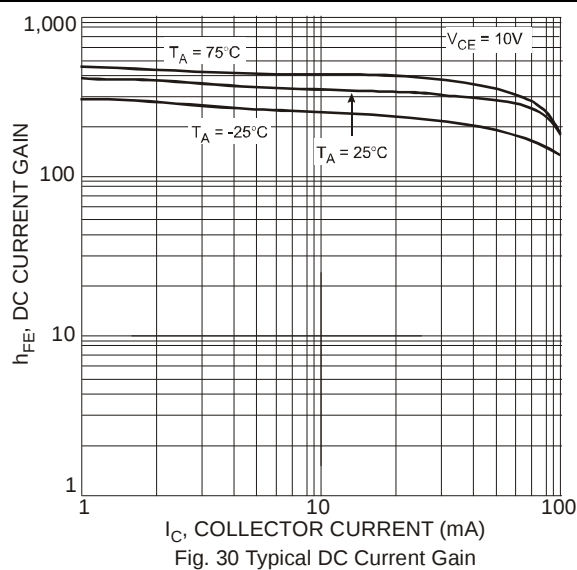
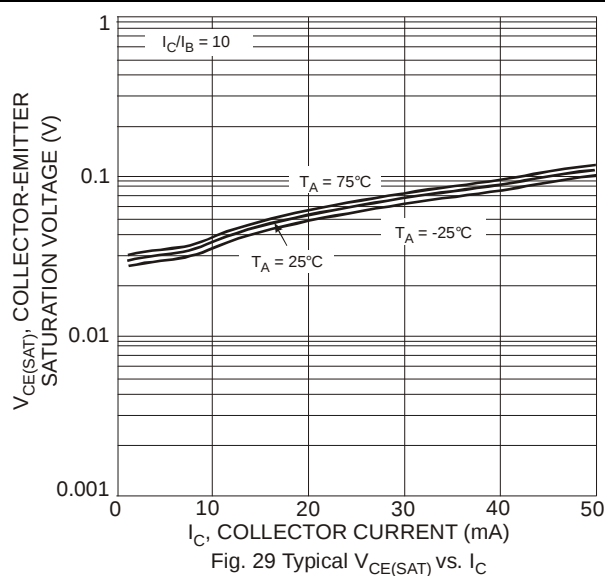
Typical Curves – DCX114TU PNP Section (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Typical Curves – DCX114TU PNP Section (Cont.)



Typical Curves – DCX114TU NPN Section (@T_A = +25°C, unless otherwise specified.)



Typical Curves – DCX114TU NPN Section (Cont.)

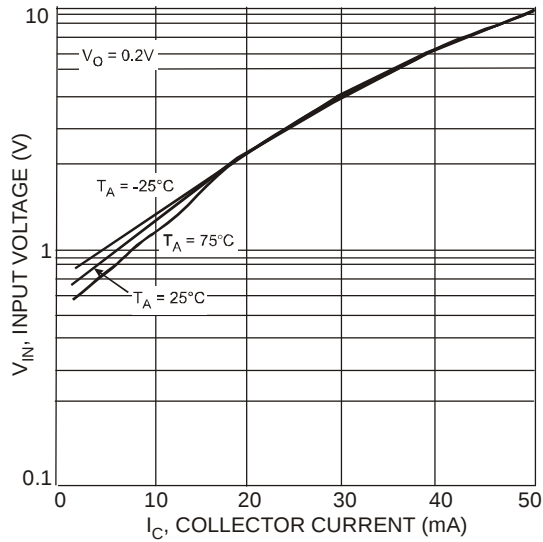
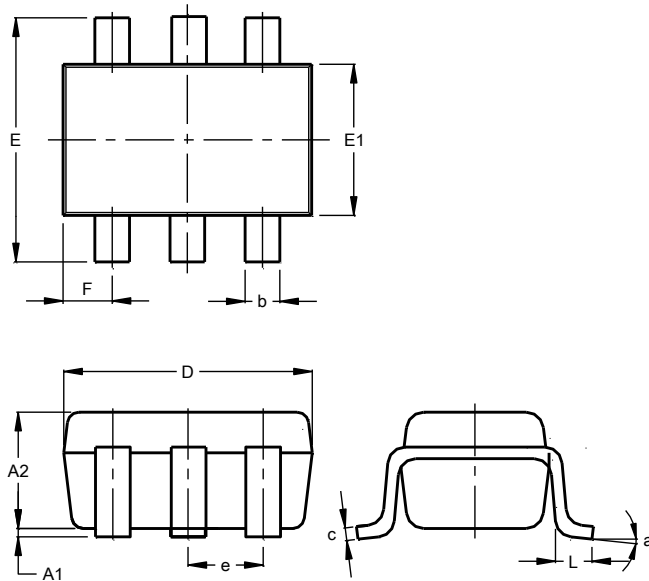


Fig. 33 Typical Input Voltage vs. Collector Current

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT363

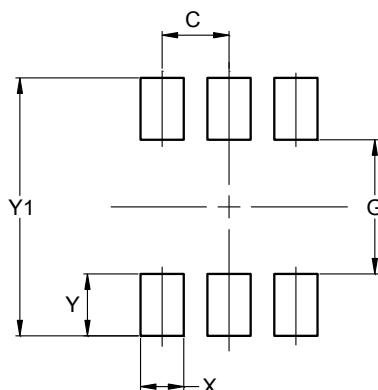


SOT363			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT363



Dimensions	Value (in mm)
C	0.650
G	1.300
X	0.420
Y	0.600
Y1	2.500

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